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(54) **LIQUID CRYSTAL DISPLAY PANEL HAVING
A LIGHT BLOCKING ELECTRODE**

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(57) **ABSTRACT**

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See (63) Related U.S. Application Data.

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Related U.S. Application Data

(63) Continuation of application No. 11/773,585, filed on
Jul. 5, 2007, now Pat. No. 8,400,599.

A liquid crystal display panel with enhanced image quality is disclosed. The liquid crystal display panel has a plurality of gate lines, a plurality of data lines, a plurality of thin film transistors connected to gate line and data line, a plurality of pixel electrodes, and floating electrode(s). The floating electrode extends along the data line to prevent light leakage and vertical crosstalk. Throughout the whole liquid crystal display panel, the floating electrode is electrically interconnected to lessen vertical crosstalk.

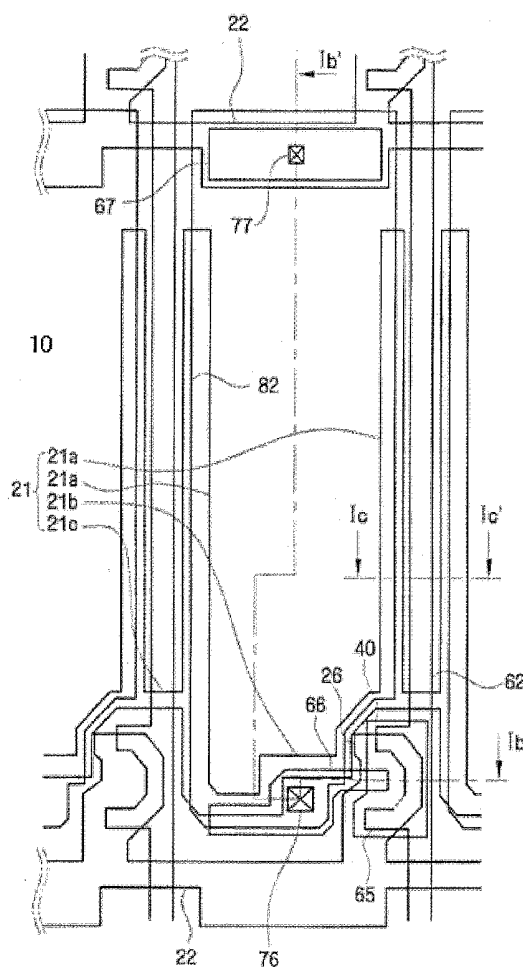


FIG. 1A

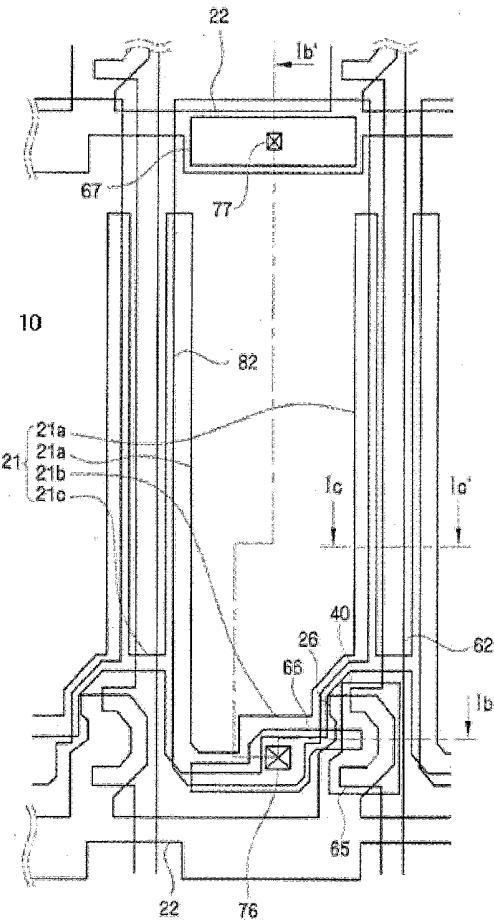


FIG. 1B

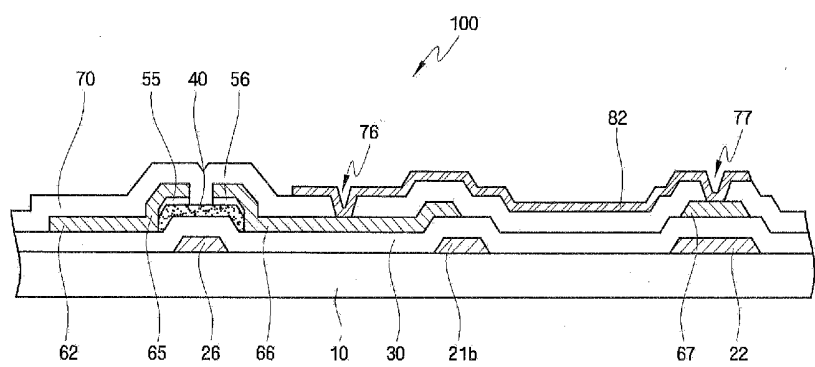


FIG. 1C

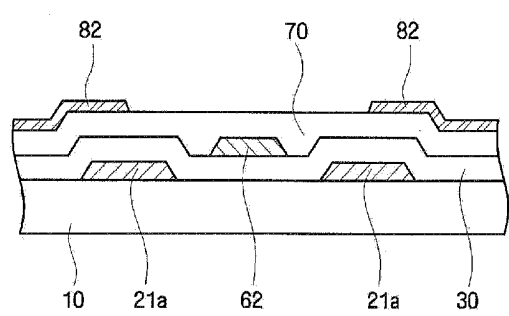


FIG. 1D

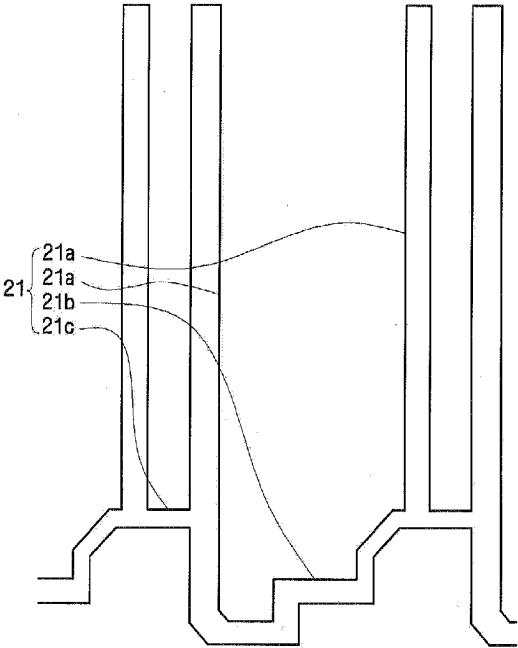


FIG. 2

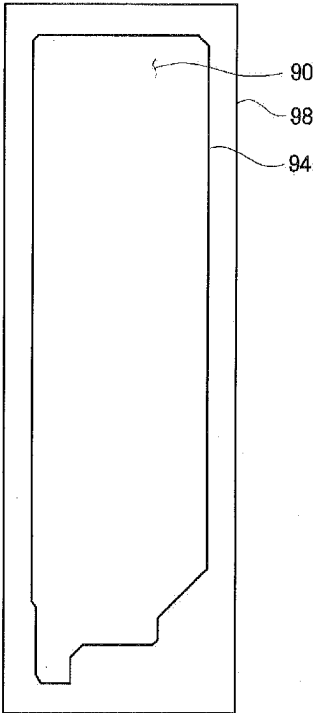


FIG. 3A

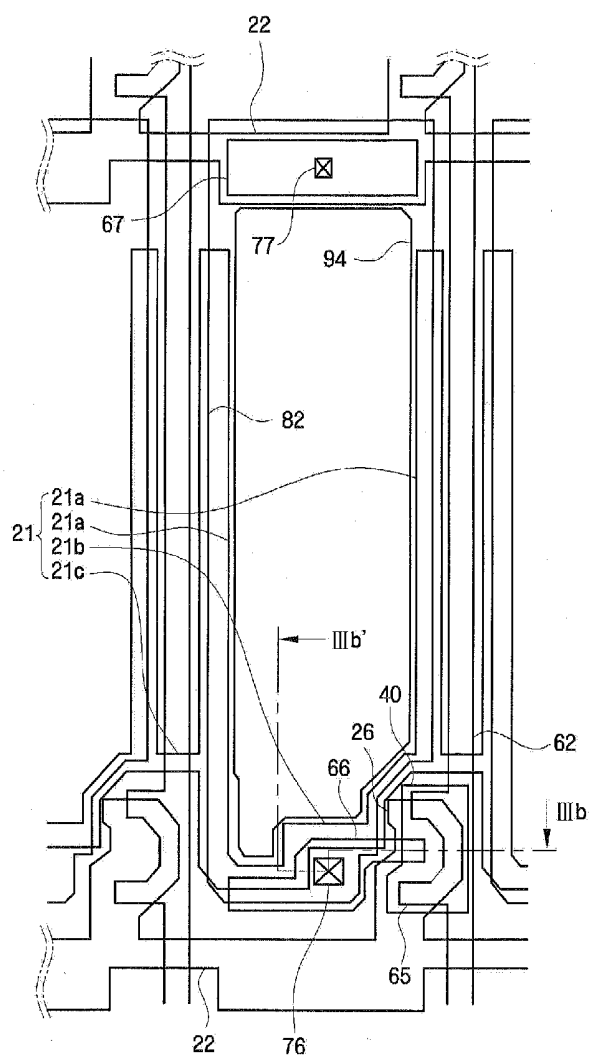


FIG. 3B

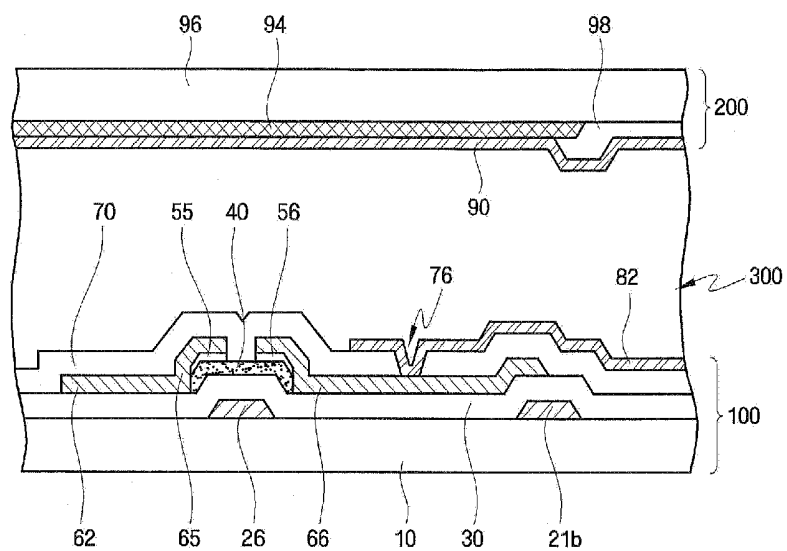


FIG. 4

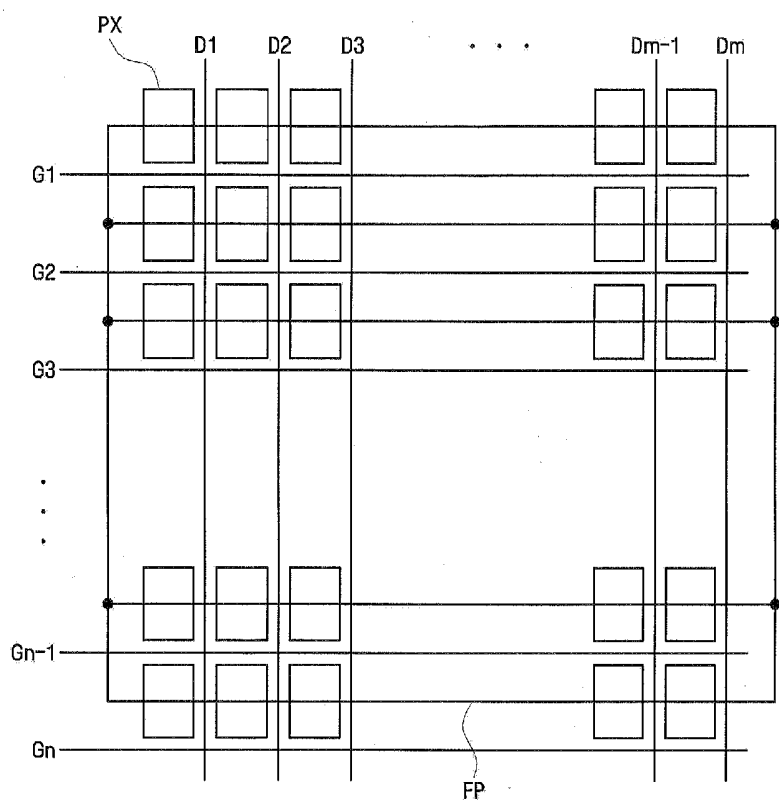


FIG. 5A

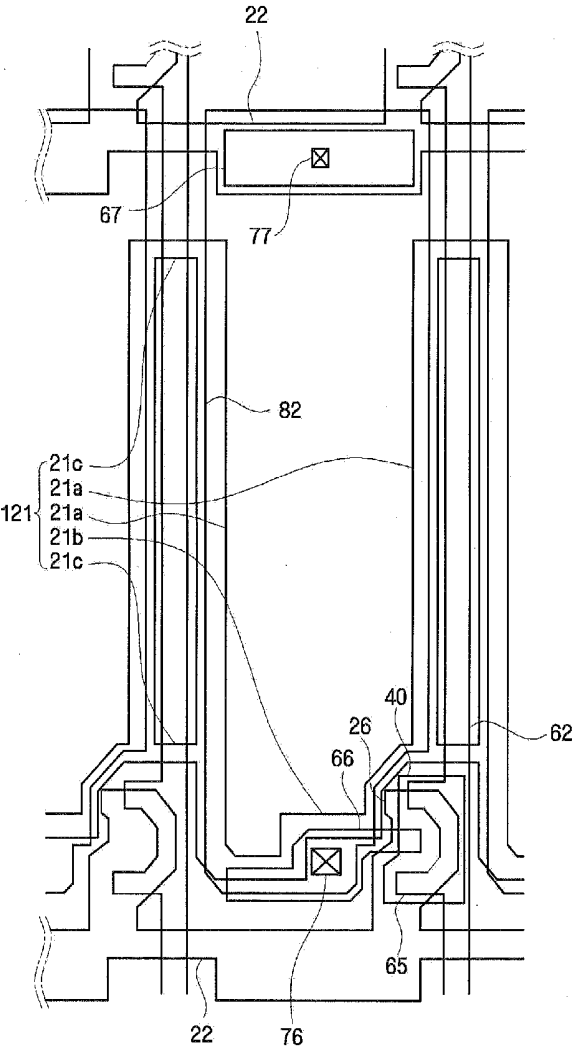


FIG. 5B

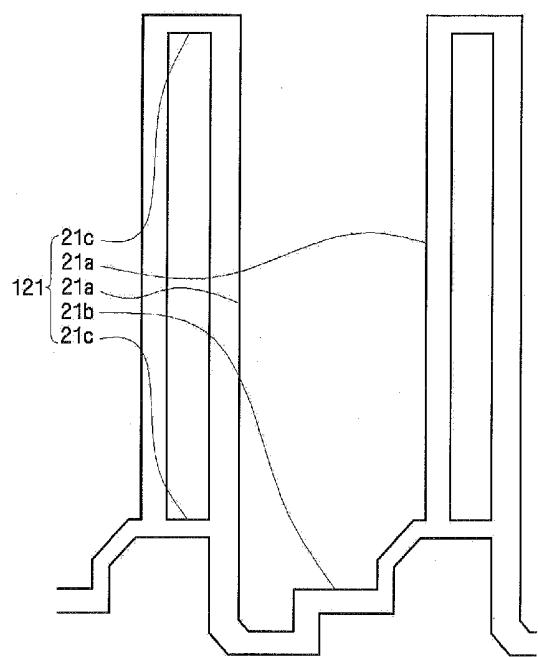


FIG. 6A

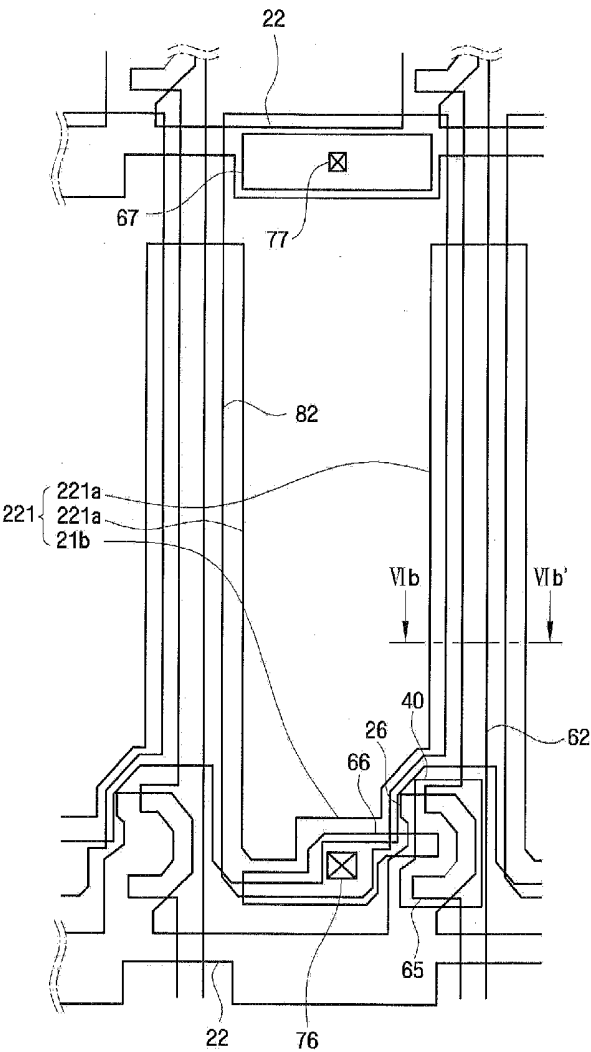


FIG. 6B

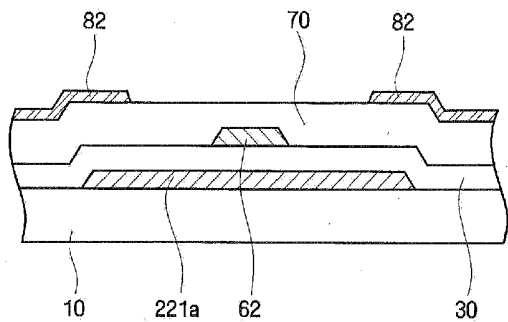


FIG. 6C

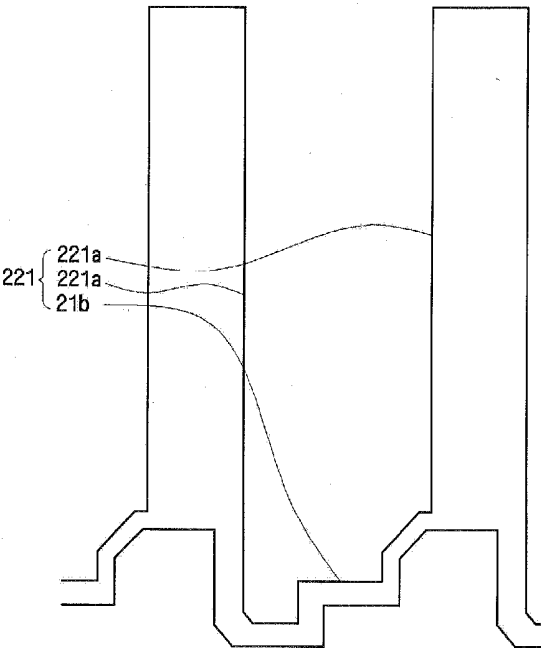


FIG. 7A

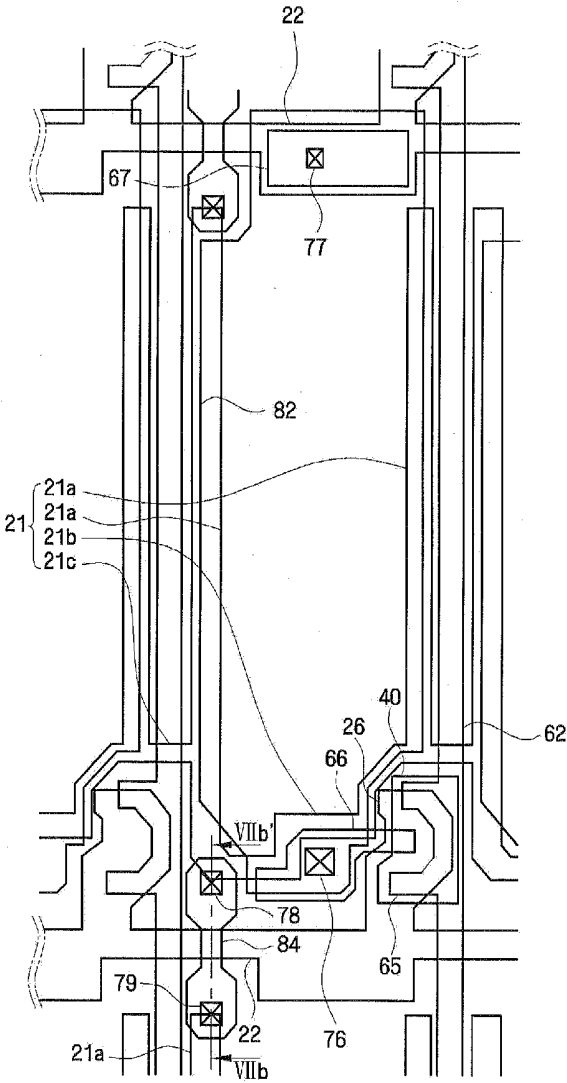


FIG. 7B

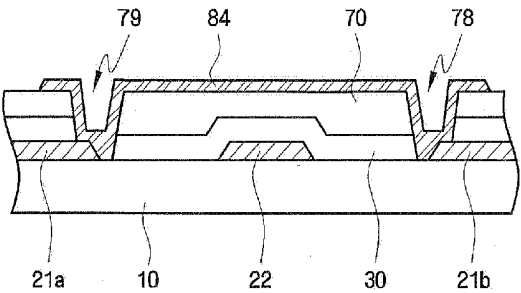


FIG. 7C

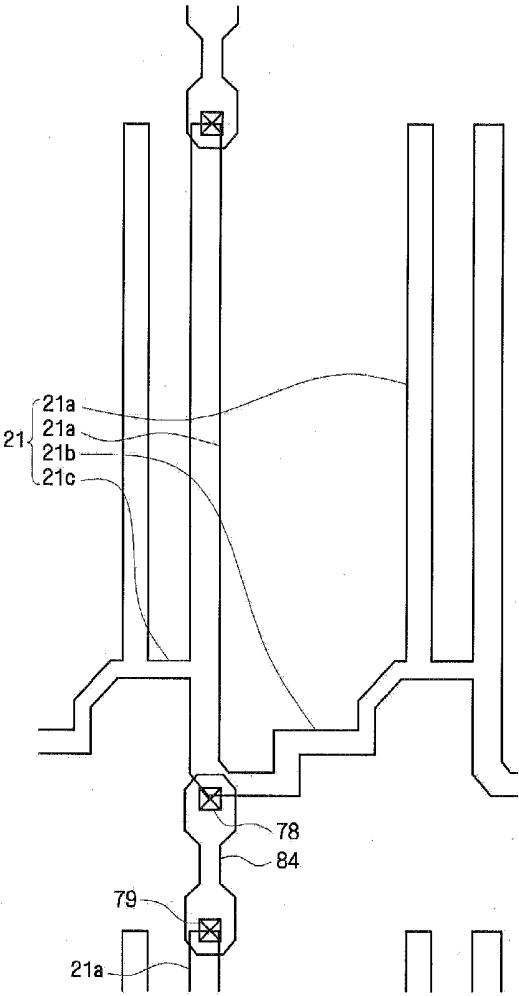


FIG. 7D

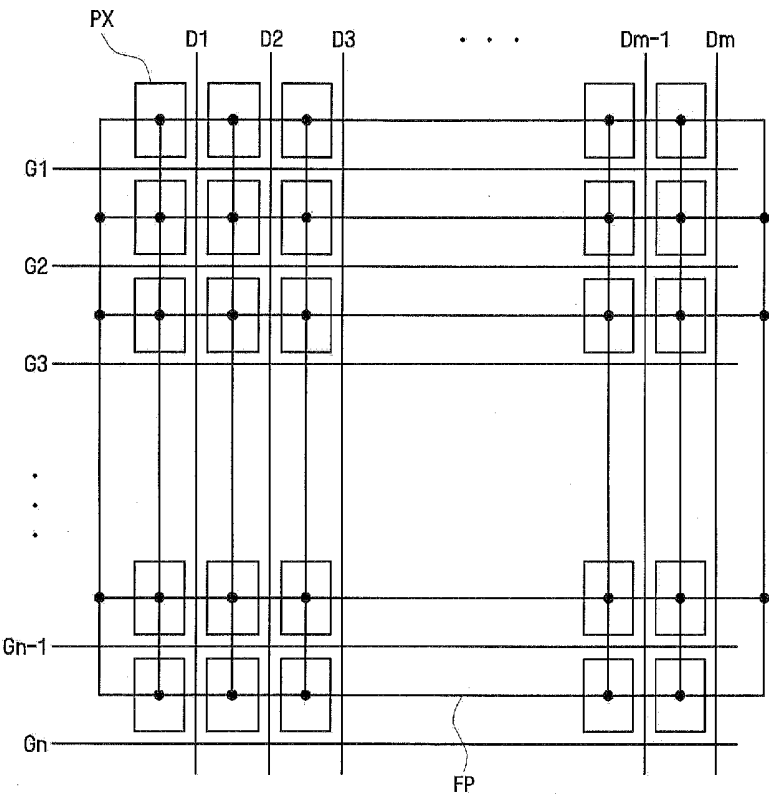


FIG. 8A

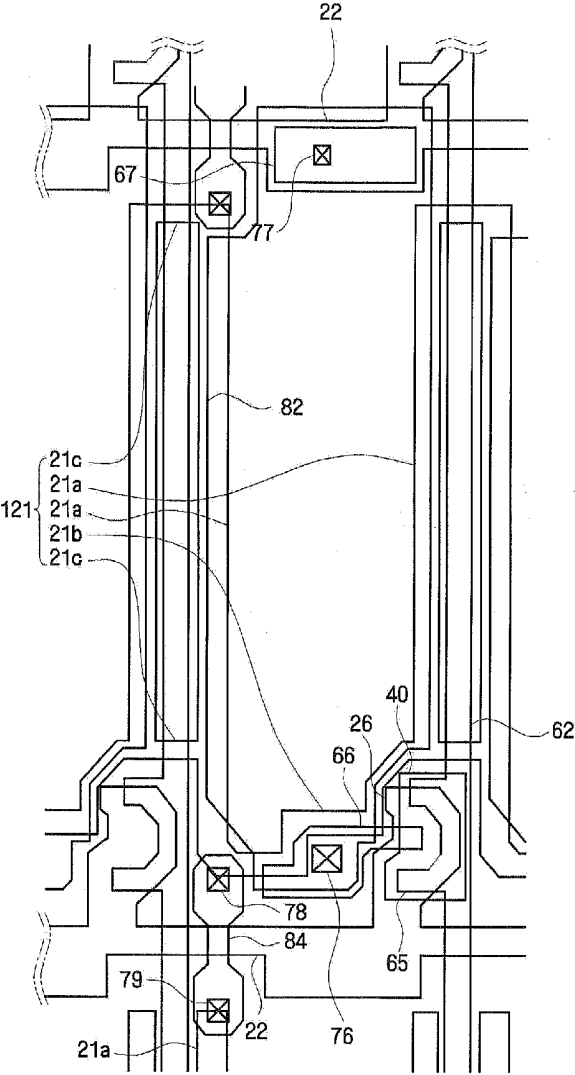


FIG. 8B

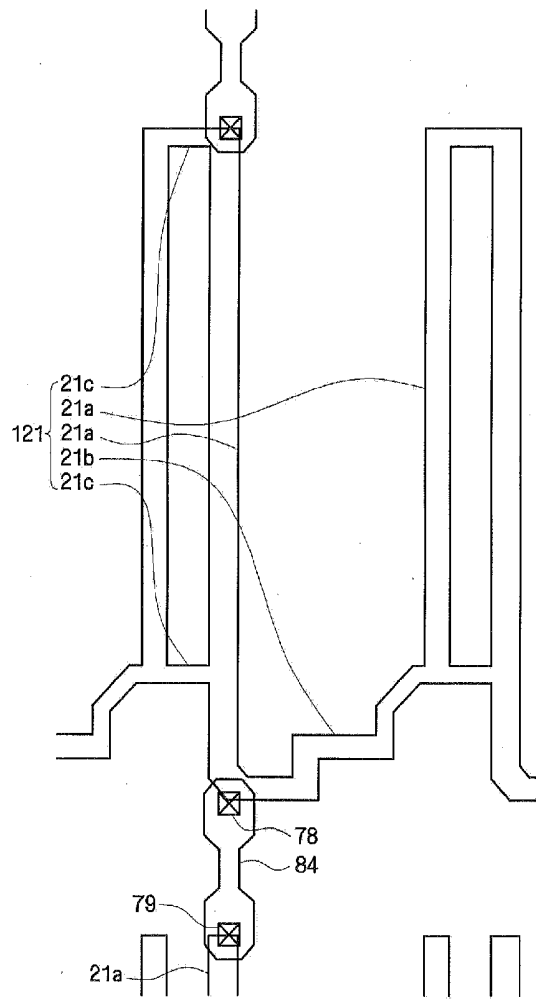


FIG. 9A

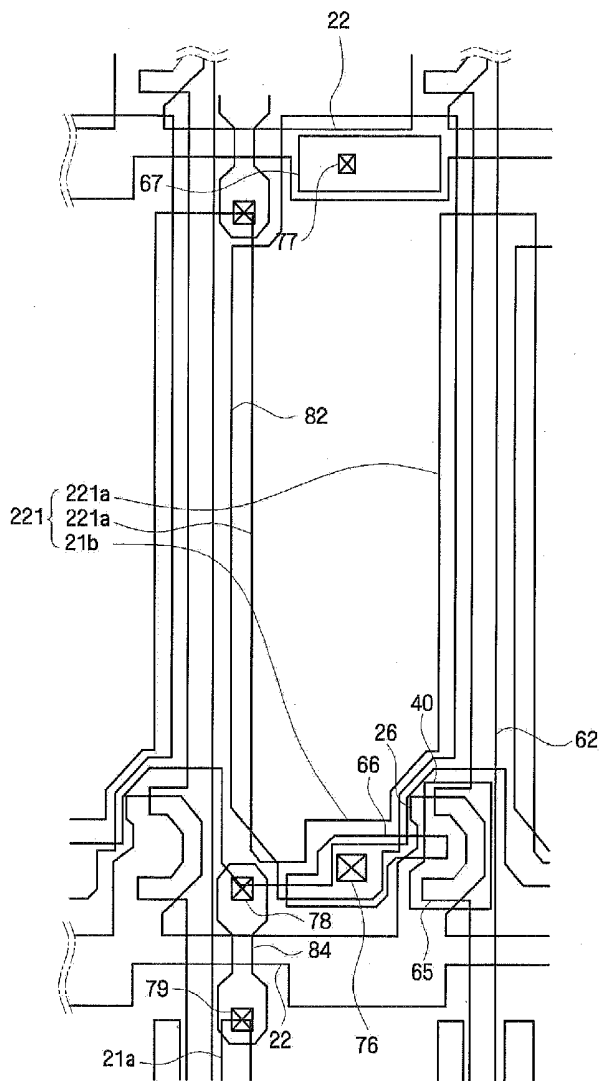
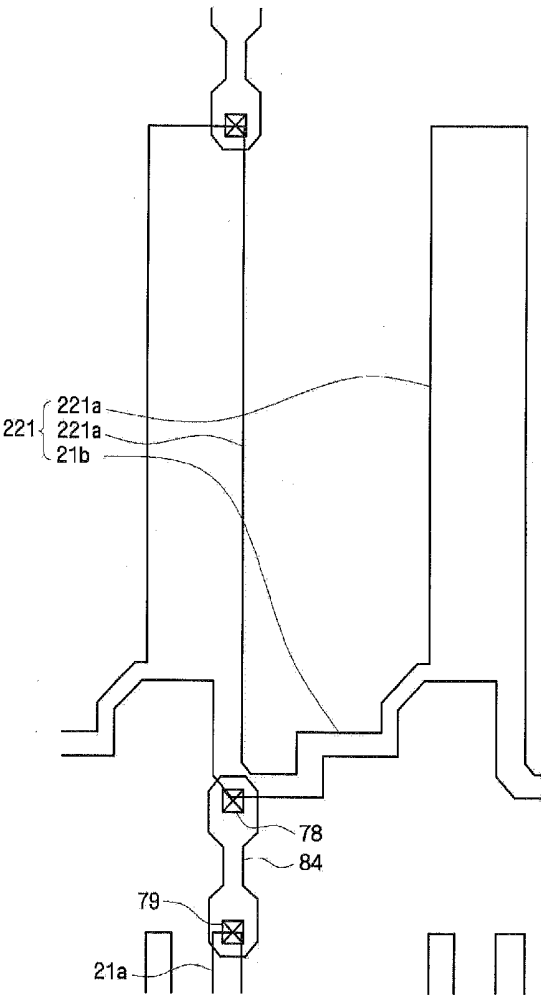


FIG. 9B



LIQUID CRYSTAL DISPLAY PANEL HAVING A LIGHT BLOCKING ELECTRODE

CROSS-REFERENCE TO RELATED PATENT APPLICATIONS

[0001] This application is a Continuation of U.S. application Ser. No. 11/733,585 filed on Jul. 5, 2007, which claims priority to Korean Patent Application Nos. 10-2006-0077135, and 10-2006-0104553, filed on Aug. 16, 2006, and Oct. 26, 2006, respectively, the disclosures of which are incorporated by reference herein in their entireties.

BACKGROUND OF THE INVENTION

[0002] 1. Field of the Invention

[0003] The present invention relates to a liquid crystal display (LCD) panel, and more particularly, the present invention relates to a LCD panel having improved image quality.

[0004] 2. Description of the Related Art

[0005] A liquid crystal display (LCD) panel comprises a pair of opposing substrates with a liquid crystal layer therebetween. One of the substrate is a common electrode substrate having a common electrode while the other substrate is a thin film transistor (TFT) substrate having a plurality of TFTs. The common electrode substrate and the TFT substrate are assembled by a seal line disposed at the edge of both the common electrode substrate and the TFT substrate. The liquid crystal layer is disposed between the common electrode substrate and the TFT substrate.

[0006] Liquid crystal molecules of the liquid crystal layer are arranged in accordance with the electricity given to the common electrode substrate and TFT substrate respectively.

[0007] The TFT substrate has a plurality of gate lines, a plurality of data lines and a plurality of pixels. Each of the gate lines extends horizontally and transmits gate signals. On the other hand, each of the data lines extends vertically and transmits data signals. Each of the pixels may be defined by one gate line and one data line and has a switching element and a storage capacitor.

[0008] A switching element may be formed near the cross point of one gate line and one data line. The switching element is a thin film transistor (TFT) with a gate electrode connected to the gate line, source electrode connected to the data line and drain electrode connected to a pixel electrode. The drain electrode may be electrically connected to a liquid crystal capacitor and to a storage capacitor.

[0009] Not being a self-emitting display device, an LCD module has a backlight unit behind the LCD panel that provides light to the LCD panel. With light provided from the backlight unit, transmittance of the LCD panel is controlled by arrangement of the liquid crystal molecules of each pixel by selectively passing light to a display image.

[0010] With the conventional LCD module of the above structure, light is apt to leak in the gap between the data line and pixel electrode to make poor image quality. Thus, to lessen the light leakage, a black matrix is generally adapted on the common electrode substrate. Specifically, the black matrix is located where the leaked light passes. However, the black matrix may result in a smaller aperture ratio of the overall LCD module to decrease the luminance of the display resulting in poor image quality.

[0011] Also, with the conventional LCD module, data signals and pixel electrodes may influence each other. Namely,

charge coupling between the data line and pixel electrode can occur causing irregular vertical crosstalk along the data line.

BRIEF SUMMARY OF THE INVENTION

[0012] Accordingly, it is an aspect of the present invention to provide a LCD module with less light leakage and charge coupling between the data line and pixel electrode to enhance image quality of LCD module.

[0013] The foregoing and/or other aspects of the present invention are achieved by providing an LCD panel including a plurality of gate lines, a plurality of data lines, a plurality of pixels and floating electrode(s).

[0014] According to one embodiment of the present invention, the floating electrode includes a light blocking pattern extending along the data line, an inter-pixel connection pattern connecting the light blocking patterns of different pixels and intra-pixel connection pattern connecting the light blocking patterns within one pixel.

[0015] According to another embodiment of the present invention, the floating electrode includes a light blocking pattern extending along the data line and a plurality of inter-pixel connection patterns each connecting the light blocking patterns of different pixels.

[0016] According to an alternate embodiment of the present invention, the floating electrode includes a light blocking pattern wider than and overlapping the data line.

[0017] According to another alternate embodiment of the present invention, the floating electrode includes a light blocking pattern and inter-pixel connection pattern connecting the light blocking patterns of horizontally neighboring pixels. Further, a bridge electrode connects the light blocking pattern of one pixel and inter-pixel connection pattern in the vertically neighboring pixel.

BRIEF DESCRIPTION OF THE DRAWINGS

[0018] The above and/or other aspects and advantages of the present invention will become apparent and more readily appreciated from the following description of the exemplary embodiments, taken in conjunction with the accompanying drawings of which:

[0019] FIG. 1A is a layout of a pixel of a thin film transistor (TFT) substrate of an exemplary embodiment according to the present invention;

[0020] FIG. 1B is a cross-sectional view of a pixel taken along a line Ib-Ib' of the exemplary embodiment of FIG. 1A according to the present invention;

[0021] FIG. 1C is a cross-sectional view of a pixel taken along a line Ic-Ic' of the exemplary embodiment of FIG. 1A according to the present invention;

[0022] FIG. 1D is a layout of a floating electrode formed on the TFT substrate of the exemplary embodiment of FIG. 1A according to the present invention;

[0023] FIG. 2 is a layout of a pixel of a common electrode substrate of an exemplary embodiment according to the present invention;

[0024] FIG. 3A is a combined layout of a pixel of a liquid crystal display (LCD) panel which is an assembly of the TFT substrate of FIG. 1A and common electrode substrate of FIG. 2 of an exemplary embodiment according to the present invention;

[0025] FIG. 3B is a cross-sectional view of the pixel taken along a line IIb-IIb' of the exemplary embodiment of FIG. 3A according to the present invention;

[0026] FIG. 4 is a simplified overall layout of the TFT substrate of the exemplary embodiment according to the present invention; FIG. 5A is a layout of a pixel of a TFT substrate of an exemplary embodiment according to the present invention;

[0027] FIG. 5B is a layout of a floating pattern formed on the TFT substrate of the exemplary embodiment of FIG. 5A according to the present invention;

[0028] FIG. 6A is a layout of a pixel of a TFT substrate of an exemplary embodiment according to the present invention;

[0029] FIG. 6B is a cross-sectional view of a pixel taken along a line VIb-VIb' of the exemplary embodiment of FIG. 6A according to the present invention;

[0030] FIG. 6C is a layout of a floating pattern formed on the TFT substrate of the exemplary embodiment of FIG. 6A according to the present invention;

[0031] FIG. 7A is a layout of a pixel of a TFT substrate of an exemplary embodiment according to the present invention;

[0032] FIG. 7B is a cross-sectional view of a pixel taken along a line VIIb-VIIb' of the exemplary embodiment of FIG. 7A according to the present invention;

[0033] FIG. 7C is a layout of a floating pattern and a bridge electrode formed on the TFT substrate of the exemplary embodiment of FIG. 7A according to the present invention;

[0034] FIG. 7D is a simplified overall layout of the TFT substrate of the exemplary embodiment of FIG. 7A according to the present invention;

[0035] FIG. 8A is a layout of a pixel of a TFT substrate of an exemplary embodiment according to the present invention;

[0036] FIG. 8B is a layout of a floating pattern and a bridge electrode formed on the TFT substrate of the exemplary embodiment of FIG. 8A according to the present invention;

[0037] FIG. 9A is a layout of a pixel of a TFT substrate of an exemplary embodiment according to the present invention;

[0038] FIG. 9B is a layout of a floating pattern and a bridge electrode formed on the TFT substrate of the exemplary embodiment of FIG. 9A according to the present invention.

DETAILED DESCRIPTION OF THE INVENTION

[0039] Reference will now be made in detail to exemplary embodiments of the present invention, examples of which are illustrated in the accompanying drawings, wherein like reference numerals refer to like elements throughout. The embodiments are described below in order to explain the present invention by referring to the figures.

[0040] The LCD panel shown in FIGS. 1A through 4 is explained according to one embodiment of the invention. The LCD panel includes a TFT substrate, a common electrode substrate and a liquid crystal layer disposed inbetween the TFT substrate and the common electrode substrate. The TFT substrate includes a plurality of gate lines, a plurality of data lines, and a plurality of TFTs electrically connected to the gate line and the data line to transmit voltage to a pixel electrode. The common electrode substrate faces the TFT substrate and includes a common electrode to control the liquid crystal layer.

[0041] FIG. 1A is a layout of a pixel of the TFT substrate. FIG. 1B is a cross-sectional view of a pixel taken along a line Ib-Ib' of FIG. 1A. FIG. 1C is a cross-sectional view of a pixel

taken along a line Ic-Ic' of FIG. 1A. At last, FIG. 1D is a layout of a floating electrode formed on the TFT substrate of FIG. 1A.

[0042] On insulating substrate 10, a gate wiring which comprises a gate line 22 and gate electrode 26 projected from gate line 22 is formed. The floating electrode 21 is formed on the insulation substrate 10 and arranged in horizontal direction with vertically extending light blocking pattern 21a near the data line 62. The floating electrode 21 of each pixel is, throughout the TFT substrate, interconnected to each other and electrically isolated from external voltage source of the TFT substrate. Alternatively, the interconnected floating electrode 21 throughout the TFT substrate is give a predetermined voltage as long as the floating electrode is effective for vertical crosstalk.

[0043] Specifically, floating electrode 21 comprises a light blocking pattern 21a, intra-pixel connection pattern 21b, and inter-pixel connection pattern 21c. The light blocking pattern 21a is located along the data line 62 to prevent light leakage between the data line 62 and a pixel electrode 82. The light blocking pattern 21a may or may not overlap with data line 62. Also, light blocking pattern 21a may or may not overlap with pixel electrode 82.

[0044] A plurality of light blocking patterns 21a may be formed within one pixel. Thus, because every pixel may have the same or similar structure within one horizontal line of the TFT substrate, every pixel may have a plurality of light blocking patterns 21a. Here, a plurality of light blocking patterns 21a is connected by an intra-pixel connection pattern 21b of floating electrode 21. Similarly, different pixel's light blocking patterns 21a are connected by an inter-pixel connection pattern 21c of floating electrode 21.

[0045] Thus, every light blocking pattern 21a is electrically connected by inter-pixel connection patterns 21c and intra-pixel connection patterns 21b within one horizontal line along gate line 22. On the other hand, the whole floating electrode 21 is not electrically connected to external voltage source.

[0046] For designing of storage capacitance of the LCD module, previous capacitance type and independent capacitance line type has been introduced. Previous capacitance type uses storage capacitance by overlapping pixel electrode 82 and previous gate's extended width, whereas independent capacitance line type uses storage capacitance by overlapping pixel electrode 82 and specially added common voltage (Vcom) line of the same gate metal. Even though the present invention is shown with previous capacitance type, the independent capacitance line type may also be used within the scope of the present invention.

[0047] On the TFT substrate, gate wiring 22, 26 and floating electrode 21 may include at least one of Al, Al alloy, Ag, Ag alloy, Cu, Cu alloy, Mo, Mo alloy, Cr, Ti and Ta. Gate wiring 22, 26 and floating electrode 21 may have a multi-layered structure with conductive layers of different physical characteristics. At least one of the multi-layered structures may be a low resistivity conductive metal of Al, Al alloy, Ag, Al alloy, Cu, or Cu alloy to reduce signal delay or voltage drop of the gate wiring 22, 26 and floating electrode 21. On the contrary, at least one layer of the multi-layered structure may be Indium Tin Oxide (ITO) or Indium Zinc Oxide (IZO) friendly material such as Mo, Mo alloy, Cr, Ti, or Ta. Exemplary combinations of low resistivity and good contact characteristics are either lower layer of Cr and upper layer of Al or lower layer of Al and upper layer of Mo. However, the gate

wiring and floating electrode material is not limited to the already introduced examples and may be any combination of various conductive materials.

[0048] On the gate wiring and floating electrode **21**, a gate insulating layer **30** is formed with insulating material such as SiNx. On the gate insulating layer **30**, semiconductor layer **40** is formed with material such as hydrogenated amorphous silicon or poly-silicon. The semiconductor layer **40** may be either line pattern or isolated pattern. The isolated pattern semiconductor layer is formed on the gate line **22** as shown in the present invention while the line pattern semiconductor layer may be formed under the data line **62** and extends to the gate line **22** with data line's **62** shape.

[0049] On the semiconductor layer **40**, resistive contact layer **55, 56** is formed with highly doped hydrogenated amorphous silicon or silicide. The resistive contact layer **55, 56** may be either line pattern or isolated pattern. For example, isolated pattern resistive contact layer can be located under the source and drain electrode as in the present invention, whereas the line pattern resistive contact layer may extend under the data line **62**.

[0050] On the resistive contact layer **55, 56** and gate insulation layer **30**, data line **62**, source electrode **65** and drain electrode **66** are formed. Data line **62** extends vertically to cross the gate line **22**. Source electrode **65** is projected from the data line **62** and extends to the semiconductor layer **40** while drain electrode **66** on the semiconductor layer is separated from and facing the source electrode **65** with gate electrode **26** in the middle. The TFT consists of the gate electrode **22**, source electrode **65** and drain electrode **66** and transmits electricity from source electrode **65** to drain electrode **66** when gate electrode **26** receives gate voltage.

[0051] Drain electrode **66** includes a bar type pattern on the semiconductor layer **40** and an extensive area that is elongated from the bar type pattern with contact hole **76**. The data line **62**, source electrode **65** and drain electrode **66** are collectively called data wiring.

[0052] Further, a capacitance electrode **67** of the same material and layer with data line **62** may be formed to overlap the previous gate line **22** by being electrically connected with the pixel electrode **82** via contact hole **77**. The combination of capacitance electrode **67**, previous gate line **22** and intervening gate insulation layer **30** can store capacitance of the liquid crystal layer.

[0053] Data wiring and the capacitance electrode **67** may be either a single layer or multi-layer including at least one of Al, Cr, Mo, Ta and Ti. For example, data wiring and capacitance electrodes may be a multi layer of Cr, Mo based material, Ta or Ti in one layer with a lower layer of Cr, Mo based material, Ta or Ti and an upper layer of low resistivity. More specifically, a lower layer of Cr and upper layer of Al, a lower layer of Al and upper layer of Mo, or a lower layer of Mo, middle layer of Al and upper layer of Mo may be used as the multi layered data wiring and capacitance electrode.

[0054] In the TFT, the confronting source electrode **65** and drain electrode **66** at least partially overlap with both gate electrode **26** and semiconductor layer **40** to transmit pixel driving voltage.

[0055] Additionally, resistive contact layer **55, 56** is sandwiched between a semiconductor layer and either the source electrode **65** or the drain electrode **66** to reduce contact resistance.

[0056] On the data wiring **62, 65, 66**, storage capacitance conductor **67** and exposed semiconductor layer **40**, a passivation layer **70** are disposed.

The passivation layer may be made of various materials such as inorganic material, organic material, or insulating material with a low dielectric constant. Here, inorganic material can be either SiNx or SiOx while organic material may be photosensitive and used for making a flat surface. Insulating material with a low dielectric constant is disposed by plasma enhanced chemical vapor deposition (PECVD) and can be either a-Si:C:O or a-Si:O:F. More than two different materials can be used for passivation layer **70**. For example, when organic material is applied, an additional bottom layer of inorganic material can be used to prevent the organic material's direct contact with exposed semiconductor layer of TFT.

[0057] Contact holes **76, 77** are formed to partially uncover either a drain electrode **66** or storage capacitance electrode **67**. On the passivation layer, pixel electrode **82** is formed along the inner line of each pixel. The pixel electrode **82** is electrically connected to the drain electrode **66** via drain electrode contact hole **76**. Further, pixel electrode **82** is electrically connected to the storage capacitance electrode **67** via storage capacitance electrode contact hole **77**.

[0058] Thus, pixel electrode **82** with a pixel driving voltage can control the arrangement of liquid crystal molecules by causing electric field in cooperation with the common electrode **90** of the common electrode substrate. Here, pixel electrode **82** is made of either transparent conductive material such as Indium Tin Oxide (ITO) and Indium Zinc Oxide (IZO) or reflective conductive material such as Al. On the pixel electrode **82** or passivation layer **70**, an orientation layer (not shown) may be disposed to setup a basic orientation of the liquid crystal molecules.

[0059] Now, referring to FIGS. 1A, 1C, and 1D, floating electrode **21** is explained in detail. In FIG. 1A, floating electrode **21** extends along data line **62** with at least a partially overlapping relationship. In addition, a part of pixel electrode closest to the data line overlaps with the floating line, too. More specifically, light blocking pattern **21a** of floating electrode **21** is disposed along the data line **62** and partially overlaps with a portion of pixel electrode **82**. Further, inter-pixel connection electrode **21c** partially overlaps with data line **62**. From here, the light blocking electrode's function is explained. Liquid crystal molecules around the data line may be undesirably arranged because the electric field from data line **62** is more dominant than the electric field from the pixel electrode. Therefore, light around the data line passes in a wrong direction and light leakage can be seen outside of the LCD panel. However, wrongly directed light can be screened by a pattern around the data line. In FIG. 1A, light blocking pattern **21a** screens the wrongly directed light and prevents light leakage.

[0060] However, the floated light blocking electrode **21a** may be electrically coupled to data line **62** and may cause irregular vertical crosstalk of LCD panel. To solve this potential problem, in the current embodiment, each of the light blocking patterns **21a** is electrically interconnected to a neighboring light blocking electrode **21a** by inter-pixel connection pattern **21c** and intra-pixel connection pattern **21b**. Now, because the unified floating electrode is not influenced or coupled by or to a specific data line, irregular vertical crosstalk may not be seen.

[0061] If the unified floating electrode **21** passes a common voltage, liquid crystal molecules around the data line may experience an undesired electric field and be arranged incorrectly because it is being influenced by a common voltage

rather than pixel electrode's voltage. Thus, floating electrode 21 is electrically independent from any other voltage to prevent light leakage.

[0062] In FIG. 2, a layout of a pixel of a common electrode substrate is introduced according to one embodiment of the present invention. Additionally, in FIG. 3A, a layout of a pixel of an assembled LCD panel with a TFT substrate, common electrode substrate and liquid crystal layer is introduced. Further, FIG. 3B shows a cross-sectional view of the LCD panel taken along a line IIIb-IIIb' of FIG. 3A.

[0063] Throughout FIGS. 2, 3A and 3B, a black matrix 94 is formed on a transparent glass substrate 96. Black matrix 94 is also disposed around each of the pixels to prevent undesired light's transmitting. Black matrix 94 may be made of at least one such as Cr, metal oxide such as CrOx and organic material. In the light passing area between neighboring black matrix 94, color filter 98 is disposed to transmit red, green or blue light. An additional overcoat layer (not shown) may be formed on the color filter layer 98 and black matrix 94 to cover an uneven color filter layer and make one flat surface. Finally, on either color filter layer 98 or overcoat layer, transparent common electrode layer 90 of ITO or IZO is formed. A supplemental orientation layer (not shown) may be coated on the common electrode layer 90 to align liquid crystal molecules around the common electrode 90.

[0064] As shown in FIG. 3B, the LCD panel has a liquid crystal layer 300 and combined TFT substrate 100 and common electrode substrate 200. In assembling, color filter 98 of common electrode substrate 200 is aligned to overlap almost exactly with pixel electrode 82 of TFT substrate 100. Then the LCD panel is completed by perpendicularly attaching a pair of polarizers on the outer surface of TFT substrate 100 and common electrode substrate 200. Finally, the LCD module is completed by assembling the LCD panel, a backlight unit behind the LCD panel and frames encompassing the LCD panel and backlight unit.

[0065] Referring to FIG. 4, floating electrode FP is explained in detail. In FIG. 4, the TFT substrate has a plurality of horizontally extending gate lines (G1, G2 . . . Gn), a plurality of vertically extending data lines (D1, D2 . . . Dm) and a plurality of pixels PX defined by each of gate lines and data lines. Throughout the whole LCD panel, each and every of the floating electrodes (FP) is interconnected between pixels in one horizontal line along each gate line and each of the horizontal lines' end points are interconnected to each other. Further, a whole floating electrode is isolated from external voltage source.

[0066] Referring to FIGS. 5A and 5B, another embodiment of present invention is explained. FIG. 5A is a layout of one pixel of the TFT substrate of the present embodiment, while FIG. 5B is a layout of a floating electrode of FIG. 5A. For a brief explanation, the same elements shown in FIGS. 1 through 4 are expressed with the same reference numeral and corresponding explanations will be omitted. Basically, every element other than the floating electrode in FIGS.

[0067] 5A and 5B is the same with the corresponding element in FIGS. 1 through 4.

[0068] In FIGS. 5A and 5B, a pair of floating electrode's light blocking pattern 21a is interconnected by a plurality of inter-pixel connection patterns 21 c. At this point, even though FIGS. 5A and 5B show two inter-pixel connection patterns, the number of inter-pixel connection patterns may be more than two.

[0069] With more than two inter-pixel connection patterns 21c, more overlap area between data line 62 and floating electrode 21 can be obtained.

[0070] The enlarged overlap area can contribute in reducing the possible overlay difference between neighboring light blocking patterns 21a of floating electrodes 21 of different pixels. Then, the reduced overlay difference may contribute in overcoming the coupling capacitance difference of each data line and each of the light blocking patterns 21a. Thus, irregular vertical crosstalk can be less recognized by a viewer.

[0071] When a semiconductor layer is extended beneath data line 62, the enlarged overlap area between data line 62 and light blocking pattern 21a can be even more efficient for image quality. In detail, light entering the data line 62 area can induce unwanted photo current to damage image quality because a photo sensitive semiconductor layer is beneath data line 62. However, with enlarged inter-pixel connection pattern 21c, the photo current can be suppressed as floating electrode 21 is formed with gate wirings to block light from entering data line 62. Accordingly, image quality can be enhanced.

[0072] Referring to FIGS. 6A through 6C, another embodiment of this invention is explained. FIG. 6A is a layout of one pixel of the TFT substrate of the present embodiment while FIGS. 6B and 6C are cross-sectional views of a pixel taken along a line VIb-VIb' of FIG. 6A and layout of floating electrode of FIG. 6A respectively. For a brief explanation, the same elements shown in FIGS. 5A and 5B are expressed with the same reference numerals and corresponding explanations will be omitted. Basically, every element other than the floating electrode in FIGS. 6A through 6C is the same as the corresponding element in FIGS. 5A and 5B.

[0073] Specifically, floating electrode 221 of FIGS. 6A through 6C consists of a light blocking pattern 221a overlapping data line 62 and inter-pixel connection pattern 21b connecting a pair of light blocking patterns 221a within one pixel. More specifically, light blocking pattern 221a may be wide enough to fully overlap in at least one horizontal direction with data line 62. Further, light blocking pattern 221a may be widened to partially overlap with a pair of pixel electrodes 82 next to one data line 62. Similar to the embodiment of FIGS. 5A and 5B, the semiconductor layer may be under the data line 62. Consequently, the widened light blocking pattern 221a may lessen the recognition of vertical crosstalk and photo leakage occurring on the semiconductor layer beneath the data line 62.

[0074] Referring to FIGS. 7A through 7D, another embodiment of this invention is explained. FIG. 7A is a layout of one pixel of the TFT substrate of the present embodiment while FIGS. 7B and 7C are cross-sectional views of a pixel taken along a line VIIb-VIIb' of FIG. 7A and a layout of the floating electrode and bridge electrode of FIG. 7A respectively. For more explanation, FIG. 7D shows a simplified LCD panel of this embodiment. To make the explanation brief, the same elements shown in FIGS. 1A through 4 are expressed with the same reference numerals and corresponding explanations will be omitted. Basically, every element other than the bridge electrode in FIGS. 7A through 7D is the same as the corresponding element in FIGS. 1A through 4.

[0075] In this embodiment of FIGS. 7A through 7D, a vertically extending bridge electrode 84 electrically connects different pixel's different floating electrodes 21. More spe-

cifically, bridge electrode **84** electrically connects the intra-pixel connecting pattern **21b** of one pixel and light blocking pattern **21a** of the other pixel.

[0076] In FIGS. 7B and 7C, floating electrodes **21a** under passivation layer **30** of two neighboring pixels are partially exposed to bridge electrode **84** for electrical connection. In this embodiment, bridge electrode **84** may be the same material with pixel electrode **82** on the same layer.

[0077] With the simplified LCD panel of FIG. 7D, floating electrode FP covers all the pixels PX of the TFT substrate which are inter connected to each other while the floating electrode is isolated from outer circuits. More specifically, floating electrode FP is formed on every row of pixels to extend in parallel with the gate lines of the TFT substrate. Each end portions of respective floating electrodes are connected to each other. Finally, respective floating electrodes are electrically connected to each other within the image display area by bridges extended in the data line direction. Consequently, every floating electrode within the display area of the panel bears uniform floating potential all over the TFT panel because horizontally extending floating electrodes are vertically connected by vertically extending bridge electrodes. Evenly distributed floating potential can prevent uneven coupling between data lines and floating electrodes of each pixel to minimize irregular vertical crosstalk by suppressing differently coupled potential between data lines and pixel electrodes of each pixel.

[0078] Referring to FIGS. 8A and 8B, another embodiment of this invention is explained. FIG. 8A is a layout of one pixel of the TFT substrate of the present embodiment; FIG. 8B is a layout of the floating electrode and bridge electrode of FIG. 8A. For a brief explanation, the same elements shown in FIG. 7A through FIG. 7D are expressed with the same reference numeral and corresponding explanations will be omitted. Basically, every element other than the shape of the floating electrode in FIGS. 8A and 8B is the same as the corresponding element in FIGS. 7A through 7D.

[0079] The floating pattern of FIGS. 8A and 8B has a pair of light blocking patterns **21a** with one data line inbetween and an inter-pixel connection pattern **21c** which connects the pair of light blocking patterns **21a**. Here, the number of inter-pixel connecting pattern may be more than one although FIGS. 8A and 8B shows one inter-pixel connection pattern.

[0080] With the enlarged overlap area between floating electrode **21** and data line **62**, the coupling capacitance difference between each light blocking pattern **21a** of floating electrode and data line **62** can be reduced when each light blocking pattern **21a** does not have the same overlay with data line **62**. Consequently, irregular vertical crosstalk is less recognized.

[0081] If the semiconductor layer is extended to beneath the data line **62**, photo leakage may be incurred by the light entering the semiconductor layer from backlight and cause poor image quality. However, the enlarged overlap area of this embodiment can screen light entering the semiconductor layer and enhance the image quality.

[0082] Referring FIGS. 9A and 9B, another embodiment of this invention is explained. FIG. 9A is a layout of one pixel of a TFT substrate of present embodiment; FIG. 9B is a layout of the floating electrode and bridge electrode of FIG. 9A. For brief explanation, the same elements shown in FIG. 8A through FIG. 8B are expressed with the same reference numeral and corresponding explanations will be omitted. Basically, every element other than the shape of floating

electrode in FIGS. 9A and 9B is the same as the corresponding element in FIGS. 8A and 8B.

[0083] The floating electrode **21** of FIGS. 9A and 9B comprises a light blocking pattern **21a** overlapping with data line **62** and an intra-pixel connecting pattern **21b**. The light blocking pattern **21a** may be wide enough to fully cover the data line **62** with a bigger width than the data line's width at least in one horizontal direction. The light blocking pattern **21a** may be also partially overlapped with pixel electrodes **82** disposed along with data line **62**.

[0084] Thus, the enlarged light blocking pattern is effective for controlling irregular vertical crosstalk. Moreover, the enlarged light blocking pattern **21a** is even more effective when the TFT substrate has a semiconductor layer under data line **62** because semiconductor layer is apt to cause a photo leakage current which adversely affects image quality.

[0085] The above-described embodiments of the present invention are merely meant to be illustrative and not limiting. It will thus be obvious to those skilled in the art that various changes and modifications may be made without departing from this invention in its broader aspects. Therefore, the appended claims encompass all such changes and modifications as fall within the true spirit and scope of this invention.

1. A liquid crystal display panel comprising:

an insulating substrate;

a plurality of gate lines extending in a first direction on the insulating substrate;

a plurality of data lines extending in a second direction that crosses with the gate lines to define a plurality of pixels;

each pixel comprising a pixel electrode connected to a thin film transistor and disposed within said pixel;

a plurality of light blocking electrodes, each light blocking electrode corresponding to a pixel, and comprising a plurality of first portions extending in the second direction, a plurality of second portions extending in the first direction and a third portion extended from the first portions, wherein the second portions and first portions are directly connected, and the third portion is formed along a boundary portion of the pixel electrode and includes a plurality of bent portions; and

a bridge electrode connecting the fast-third portion of a third pixel and the second first portion of a fourth pixel disposed next to the third pixel in the second direction, wherein a first pixel and a second pixel are next to each other in the first direction and wherein the third portion connects a plurality of the first portions within the first pixel,

wherein the first portion of the light blocking electrode of the first pixel and the first portion of the light blocking electrode of the second pixel extend substantially parallel along opposite sides of a data line and are interconnected across the data line via interconnected second portions of the first and second pixels,

wherein the third portion extends in a direction that is different from an extension direction of the first portions at a point where the third portion meets the first portions.

2. The liquid crystal display panel of claim 1, wherein the bridge electrode crosses the gate electrode.

3. The liquid crystal display panel of claim 1, wherein the bridge electrode connects the third portion of the third pixel and the first portion of the fourth pixel via contact holes.

4. The liquid crystal display panel of claim 3, wherein the third pixel has a first contact hole exposing the third portion of

the light blocking electrode and wherein the fourth pixel has a second contact hole exposing the first portion of the light blocking electrode.

5. (canceled)

6. The liquid crystal display panel of claim 1, wherein the bridge electrode is the same layer with the pixel electrode.

7. The liquid crystal display panel of claim 1, wherein the bridge electrode is the same material with the pixel electrode.

8. The liquid crystal display panel of claim 7, wherein the material is a transparent conductive oxide.

9. The liquid crystal display panel of claim 8, wherein the transparent conductive oxide is selected from IZO and ITO.

10. The liquid crystal display panel of claim 1, wherein the bridge electrode is of dumbbell shape.

11. The liquid crystal display panel of claim 10, wherein the bridge electrode has two contact portions that contact with the contact holes and a connecting portion that connects the

contact portions, and wherein the contact portions have larger width than the connecting portion.

12. The liquid crystal display panel of claim 1, wherein the light blocking electrodes are disposed and interconnected in a series of pixels in the first direction to form a first light blocking electrode line and a second light blocking electrode line, wherein the first light blocking electrode line and the second light blocking electrode line are in different series of pixels, wherein the first light blocking electrode line has a first end point and a second end point, and wherein the second light blocking electrode line has a third end point and a fourth end point, wherein the first end point and the third end point are at a first side of the substrate and interconnected and/or wherein the second end point and the fourth end point are at a second side of the substrate and interconnected.

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专利名称(译)	具有光阻电极的液晶显示面板		
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申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
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摘要(译)

公开了一种具有增强图像质量的液晶显示面板。液晶显示面板具有多条栅极线，多条数据线，连接到栅极线和数据线的多个薄膜晶体管，多个像素电极和浮动电极。浮动电极沿数据线延伸，以防止漏光和垂直串扰。在整个液晶显示板中，浮动电极电互连以减少垂直串扰。

